


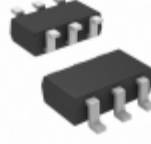





	<h2>SI3483DV-T1-E3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI3483DV-T1-E3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 30V 4.7A 6-TSOP</p> <p><b>Datenblätter:</b>  <a href="#">SI3483DV-T1-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 19305 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	SI3483DV-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 30V 4.7A 6-TSOP
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	19305 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	1.14W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.7A (Ta)
Rds On (Max) @ Id, Vgs	35 mOhm @ 6.2A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	35nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI3483DV-T1-E3 ist neu im Original, Suche SI3483DV-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3483DV-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3483DV-T1-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI3484-A01-GM</b> Energy Micro (Silicon Labs) PSE POWER MANAGEMENT IC</p>	 <p><b>SI3483DV-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 30V 4.7A 6-TSOP</p>	 <p><b>SI3483DV-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 30V 4.7A 6-TSOP</p>	 <p><b>SI3483-A02-GMR</b> Energy Micro (Silicon Labs) IC POE PSE 64PORT 24QFN</p>
 <p><b>SI3483CDV-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 30V 8A 6-TSOP</p>	 <p><b>SI3484-A01-GMR</b> Energy Micro (Silicon Labs) POWER MANAGEMENT IC</p>	 <p><b>SI3483DV-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 30V 4.7A 6-TSOP</p>	 <p><b>SI3483CDV-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 30V 8A 6-TSOP</p>

### heiße Teile

Mehr

 SI3473DV-T1-E3	 SI3473DV-T1-E3	 SI3473DV-T1-GE3	 SI3473DV-T1-GE3	 SI3474DV-T1-GE3
 SI3474DV-T1-GE3	 SI3475DV-T1-E3	 SI3475DV-T1-E3	 SI3475DV-T1-GE3	 SI3475DV-T1-GE3
 SI3476DV-T1-E3	 SI3476DV-T1-GE3	 SI3476DV-T1-GE3	 SI3477DV-T1-E3	 SI3477DV-T1-GE3
 SI3477DV-T1-GE3	 SI3481DV-T1-E3	 SI3481DV-T1-E3	 SI3481DV-T1-GE3	 SI3481DV-T1-GE3
 SI3483CDV-T1-E3	 SI3483CDV-T1-E3	 SI3483CDV-T1-GE3	 SI3483CDV-T1-GE3	 SI3483DV-T1-E3
 SI3483DV-T1-GE3	 SI3483DV-T1-GE3	 SI3493BDV-T1-E3	 SI3493BDV-T1-E3	 SI3493BDV-T1-E3-S
 SI3493BDV-T1-GE3	 SI3493BDV-T1-GE3	 SI3493DDV-T1-GE3	 SI3493DDV-T1-GE3	 SI3493DV
 SI3493DV-T1	 SI3493DV-T1-E3	 SI3493DV-T1-E3	 SI3493DV-T1-E3	 SI3493DV-T1-GE3
 SI3493DV-T1-GE3	 SI3495DV	 SI3495DV-T1-E3	 SI3495DV-T1-E3	 SI3495DV-T1-GE3
 SI3495DV-T1-GE3	 SI3499DV-T1-E3	 SI3499DV-T1-E3	 SI3499DV-T1-GE3	 SI3499DV-T1-GE3

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